# NSN 5961-00-467-1599

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**Inclosure Material:** 

Metal

**Overall Length:** 

0.400 inches

# **Overall Diameter:**

0.437 inches

## **Mounting Facility Quantity:**

1

## Internal Configuration:

Junction contact

# Electrode Internally-electrically Connected To Case:

Collector

#### **Mounting Method:**

Threaded stud

Features Provided:

Hermetically sealed case

#### **Overall Width Across Flats:**

Between 0.424 inches and 0.437 inches

#### Thread Size:

0.190 inches

# Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

80.0 collector to base voltage, dc and 60.0 collector to emitter voltage, dc and 5.0 emitter to base voltage, dc

## **Current Rating Per Characteristic:**

Between 3.00 amperes source cutoff current and 10.00 amperes source cutoff current

## **Power Rating Per Characteristic:**

25.0 watts small-signal input power, common-collector preset

## **Special Features:**

Junction pattern arrangement: npn

## Test Data Document:

24587-3041-05-2800 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,

etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## Thread Series Designator:

Unf

## **Terminal Type And Quantity:**

4 tab, solder lug

Shelf Life:

N/a

#### Unit Of Measure:

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#### Demilitarization:

No

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